

WTMH80T16R

SCR Module Rev.01 - 02 January 2024

**Product data sheet** 

### **1. General description**

Planar passivated Silicon Controlled Rectifier (SCR) module in TO-240AA for use in applications requiring high blocking voltage capability, high inrush current capability and high thermal cycling performance

### 2. Features and benefits

- High blocking voltage capability
- High thermal cycling performance
- Planar passivated for voltage ruggedness and reliability
- Package meets UL certification
- Package is RoHS compliant
- Industry standard outline
- Soldering pins for PCB mounting
- Copper base plate
- Cathode Kelvin contacts provided
- UL1557 certified (Document number E346397)

## 3. Applications

- Softstart AC motor control
- DC Motor control
- AC power control
- Power converter
- Temperature control
- Lighting control

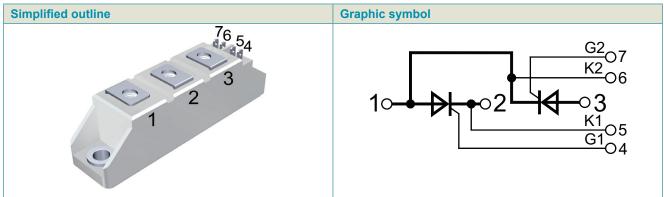
### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Values		Unit
Absolute	e maximum rating						
V <sub>DRM</sub>	repetitive peak forward voltage				1600		V
V <sub>RRM</sub>	repetitive peak reverse voltage				1600		V
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave			125		А
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 10 ms			1700		А
		half sine wave; T <sub>j(init)</sub> = 150 °C; t <sub>p</sub> = 10 ms			1400		А
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms			1850		А
		half sine wave; $T_{j(init)}$ = 150 °C; $t_p$ = 8.3 ms			1500		А
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C		30	-	100	mA
V <sub>gt</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C		-	0.70	1.20	V
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 80 A; T <sub>i</sub> = 25 °C		-	-	1.29	V

## 5. Pinning information

Table 2. Pinning information



## 6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WTMH80T16R	TO-240AA	WTMH80T16RT	Tray	12	WeEnPACK- 20mmPHB-C	30-Jun-2023

## 7. Marking

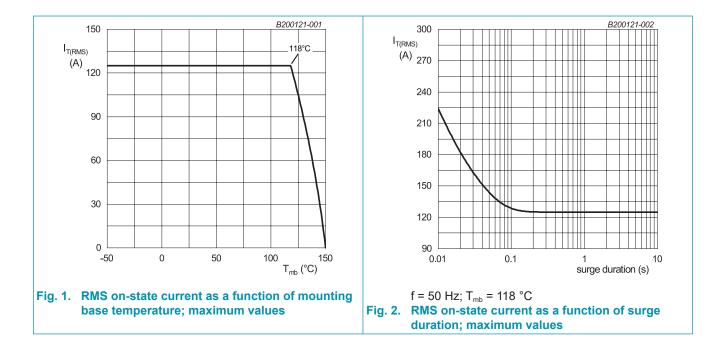
Table 4. Marking codes						
Type number	Marking codes					
WTMH80T16R	WTMH80T16R					

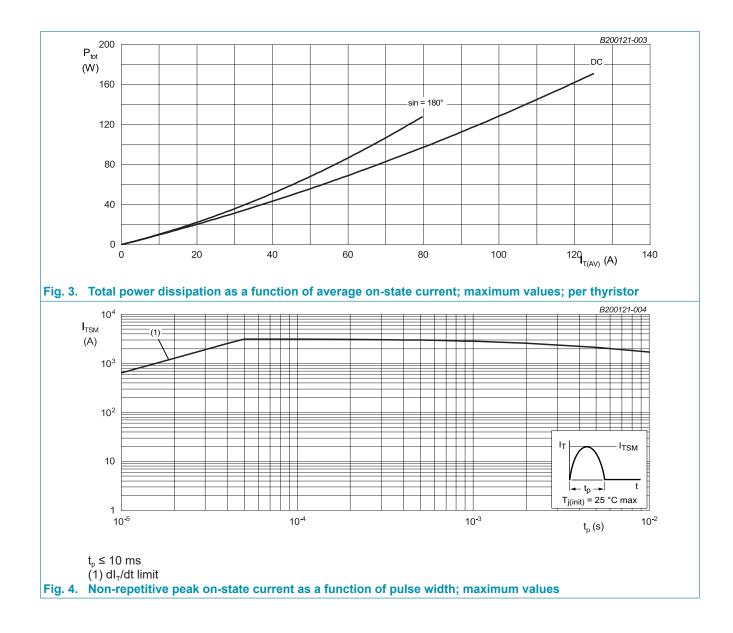
## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V <sub>DRM</sub>	repetitive peak forward voltage			1600	V
V <sub>RRM</sub>	repetitive peak reverse voltage			1600	V
$I_{T(AV)}$	average on-state current	half sine wave		80	А
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave		125	А
I <sub>TSM</sub>	non-repetitive peak onstate	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms		1700	А
	current	half sine wave; $T_{j(init)}$ = 150 °C; $t_p$ = 10 ms		1400	А
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms		1850	А
		half sine wave; $T_{j(init)}$ = 150 °C; $t_p$ = 8.3 ms		1500	А
l²t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sine-wave pulse		12.8	kA²s
dl⊤/dt	rate of rise of on-state current	I <sub>G</sub> = 200 mA; T <sub>j</sub> = 150 °C		200	A/µs
I <sub>GM</sub>	peak gate current			10	А
V <sub>RGM</sub>	peak reverse gate voltage			5	V
P <sub>GM</sub>	peak gate power			20	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period		0.5	W
T <sub>vj</sub>	virtual junction temperature			-40 to 150	°C
T <sub>op</sub>	operation temperature			-40 to 130	°C
T <sub>stg</sub>	storage temperature			-40 to 130	°C

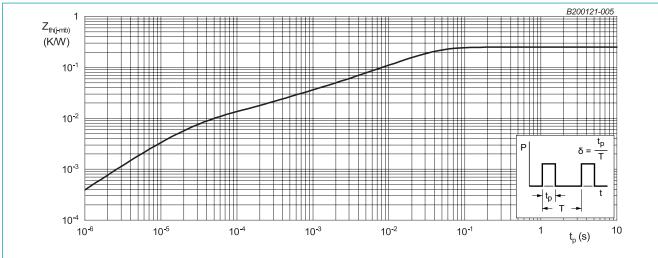




# 9. Thermal characteristics

#### Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
· -un(j-c) ······	thermal resistance from junction to case	per thyristor		-	-	0.25	K/W
		per module		-	-	0.125	K/W
	thermal resistance from junction to heatsink	per thyristor		-	-	0.48	K/W
		per module		-	-	0.24	K/W



### Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

## **10. Package characteristics**

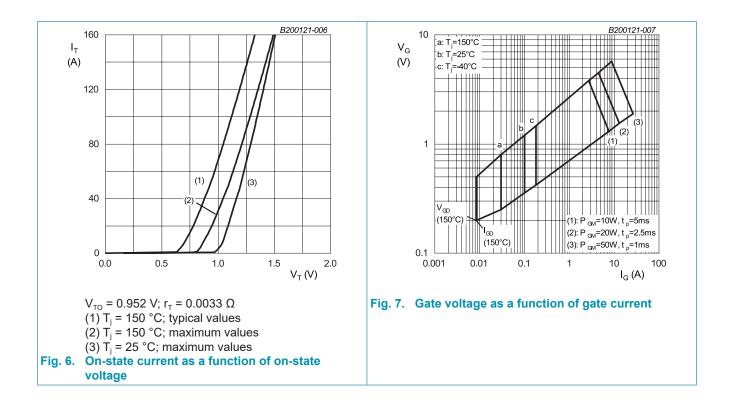
Table 7. Isolation characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
V <sub>isol</sub>	isolation voltage	50/60 Hz; RMS; I <sub>ISOL</sub> ≤ 1 mA; t = 1 second; AC		-	-	3600	V
		50/60 Hz; RMS; $I_{ISOL} \le 1$ mA; t = 1 minute; AC		-	-	3000	V

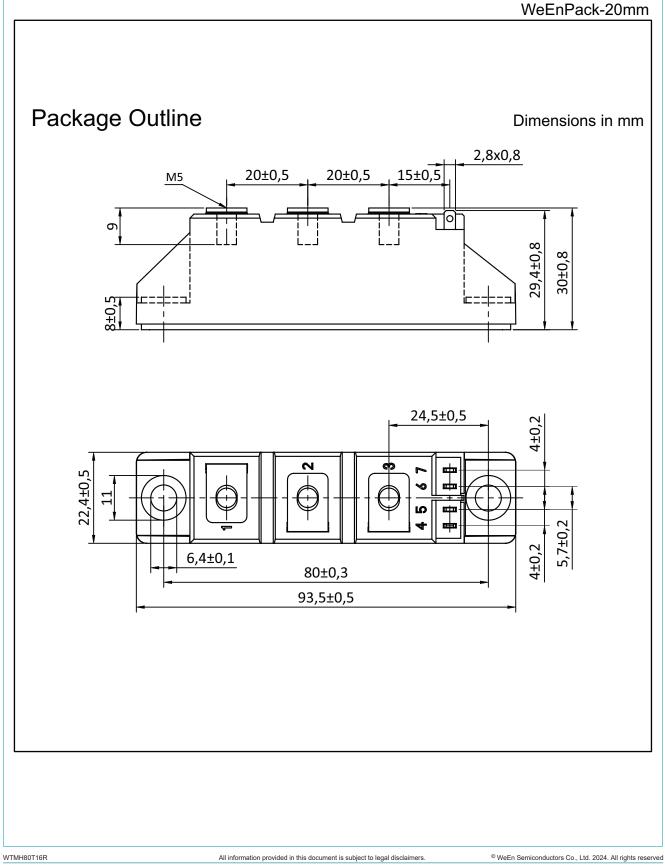
# **11. Characteristics**

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C		30	-	100	mA
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C		-	0.70	1.20	V
		$V_{\rm D}$ = 2/3 $V_{\rm DRM}$ ; $I_{\rm T}$ = 0.1 A; $T_{\rm j}$ = 150 °C		0.25	0.4	-	V
I <sub>GD</sub>	gate non-trigger current	T <sub>j</sub> = 150 °C		-	-	8.5	mA
$V_{\text{GD}}$	gate non-trigger voltage	T <sub>j</sub> = 150 °C		-	-	0.2	V
I <sub>L</sub>	latching current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C		-	-	300	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C		-	-	200	mA
V <sub>T</sub> on	on-state voltage	I <sub>T</sub> = 80 A; T <sub>j</sub> = 25 °C		-	-	1.29	V
		I <sub>T</sub> = 160 A; T <sub>j</sub> = 25 °C		-	-	1.51	V
V <sub>TO</sub>	threshold voltage	T <sub>j</sub> = 150 °C		-	-	0.95	V
r <sub>T</sub>	slope resistance	T <sub>j</sub> = 150 °C		-	-	3.3	mΩ
I <sub>D</sub>	off-state current	V <sub>D</sub> = 1600 V; T <sub>j</sub> = 25 °C		-	-	100	μA
		V <sub>D</sub> = 1600 V; T <sub>j</sub> = 150 °C		-	-	10	mA
I <sub>R</sub>	reverse current	V <sub>R</sub> = 1600 V; T <sub>j</sub> = 25 °C		-	-	100	μA
		V <sub>R</sub> = 1600 V; T <sub>j</sub> = 150 °C		-	-	10	mA
Dynamic	characteristics	1	_				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 1072 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit		1500	-	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$ I_{TM} = 40 \text{ A}; \text{ V}_{D} = 800 \text{ V}; \text{ I}_{G} = 100 \text{ mA}; \\ (dI_{G}/dt)_{M} = 1 \text{ A}/\mu\text{s}; \text{ T}_{j} = 25 ^{\circ}\text{C} $		-	2	-	μs
t <sub>q</sub>	commutated turn-off time	I <sub>TM</sub> = 2 A; t <sub>p</sub> = 50 μs; dV/dt = 5 V/μs; dI/dt = 30 A/μs; T <sub>i</sub> = 25 °C		-	150	-	μs

WTMH80T16R SCR Module



# 12. Package outline



# 13. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [2] The term 'short data sheet' is explained in section "Definitions".
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